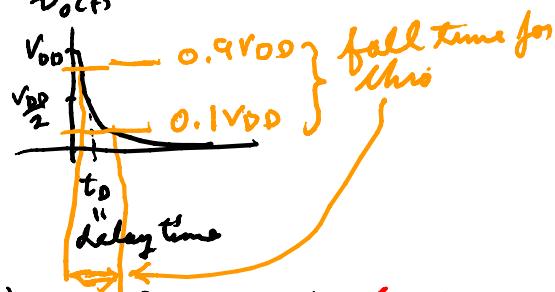
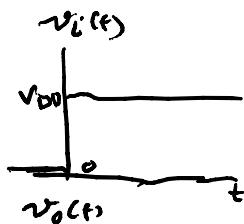
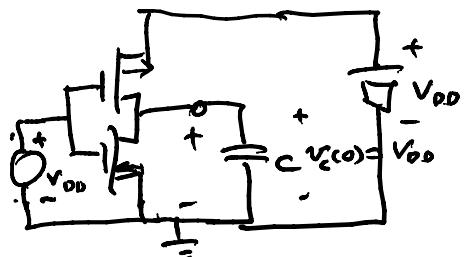


Today's homework now due Th

EE303  
03/02/10

$$t_2 - t_1 = \frac{1}{\frac{K_P W}{2 L} \cdot \frac{C}{2}} \left[ \ln \left( 1 - \frac{2(V_{DD} - V_{TO})}{V_o(t_2)} \right) - \ln \left( 1 - \frac{2(V_{DD} - V_{TO})}{V_o(t_1)} \right) \right]$$



$$t_2 - t_1 = \frac{C}{\frac{K_P W}{2} \cdot 2(V_{DD} - V_{TH})} \ln \left[ \frac{V_o(t_2) - 2(V_{DD} - V_{TO})}{V_o(t_1) - 2(V_{DD} - V_{TO})} \cdot \frac{V_o(t_1)}{V_o(t_2)} \right] \text{ when in ohmic}$$

$$t_1 = \frac{C V_{TO}}{I_D} \text{ when in saturation}$$

numerical evaluation

$$V_{DD} = 9, V_{TO} = 0.8, C = 10 \text{ pF}, W/h = 1, K_P = 2 \times 10^{-5} \\ = V_{TH}$$

$$V_{DD} - V_{TO} = 8.2, 0.1 \times V_{DD} = 0.9, 0.9 \times V_{DD} = 8.1$$

$$I_D = \frac{K_P W}{2 L} (V_{DD} - V_{TO})^2 = 10^{-5} \times (8.2)^2$$

$$t_1 = \frac{10 \times 10^{-12} \times (0.8)}{10^{-5} \times (8.2)^2} = 10^{-6} \times \frac{(0.8)}{(8.2)^2} = 0.0119 \times 10^{-6} \\ = 0.0119 \mu \text{sec}$$

$$\text{delay time} = t_2 - t_1 + t_1 \text{ for } V_o(t_2) = V_{DD}/2, V_o(t_1) = V_{DD} - V_{TO}$$

$$t_2 - t_1 = \frac{C}{\frac{K_P W}{2} \cdot 2(V_{DD} - V_{TO})} \times \ln \left[ \frac{\frac{V_{DD}}{2} - 2(V_{DD} - V_{TO})}{(V_{DD} - V_{TO}) - 2(V_{DD} - V_{TH})} \cdot \frac{V_{DD} - V_{TO}}{V_{DD}/2} \right]$$

$$= \frac{10 \times 10^{-12}}{2 \times 10^{-5} (8.2)} \times \ln \left[ \frac{4.5 - 2(8.2)}{-2} \cdot \frac{1}{4.5} \right] = \frac{10^{-6}}{1.64 \times 10} \times \ln \left[ \frac{5.95}{4.5} \right]$$

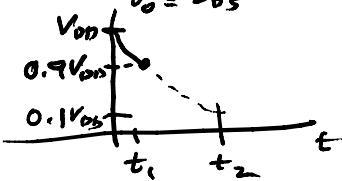
$$= \frac{10^{-7}}{1.64} \times 0.279 = 1.7 \times 10^{-8} = 0.017 \mu \text{sec}$$

$$\text{delay} = 0.0119 + 0.017 = 0.029 \mu \text{sec}$$

for 10-90% fall time: to check state of inverter  
NMOS

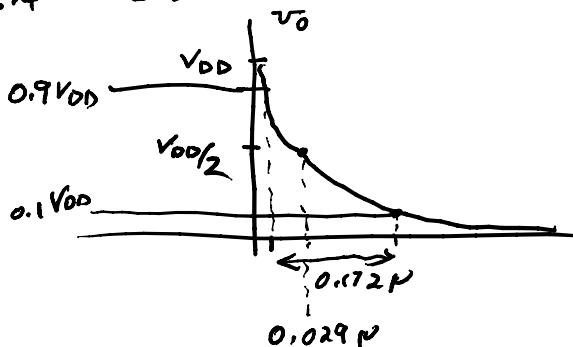
$$V_{DS} = 0.9 \times V_{DD} = 8.1 \text{ V}$$

$$V_{GS} - V_{TO} = 9 - 0.8 = 8.2 \text{ V} > V_{DS} \Rightarrow \text{in ohmic region}$$



$t_2 - t_1$  for 10-90% fall time

$$\begin{aligned} &= \frac{C}{\frac{K_P W}{L} \cdot 2(V_{DD} - V_{TO})} \ln \left[ \frac{0.1V_{DD} - 2(V_{DD} - V_{TO})}{0.9V_{DD} - 2(V_{DD} - V_{TO})} \cdot \frac{0.9V_{DD}}{0.1V_{DD}} \right] \\ &= \frac{10 \times 10^{-12}}{2 \times 10^{-5}(8.2)} \ln \left[ \frac{0.9 - 2(8.2)}{8.1 - 2(8.2)} \cdot 9 \right] = \frac{10^{-6}}{16.4} \ln \left[ \frac{0.9 - 16.4}{8.1 - 16.4} \times 9 \right] \\ &= \frac{10^{-6}}{16.4} \ln \left[ \frac{15.5}{8.3} \times 9 \right] = 10^{-6} \cdot \frac{2.822}{16.4} = 0.172 \text{ psec} \end{aligned}$$



to include Early effect

$$i_D = \frac{K_P W}{L} \left\{ \begin{array}{l} (V_{GS} - V_{TO})^2 (1 + \lambda V_{DS}) \quad \text{saturation} \\ [2(V_{GS} - V_{TO})V_{DS} - V_{DS}^2] (1 + \lambda V_{DS}) \quad \text{ohmic} \end{array} \right.$$

$$i_D = \left( \frac{K_P W}{L} \cdot \lambda \right) V_{DS} [2(V_{GS} - V_{TO}) - V_{DS}] \left( \frac{1}{\lambda} + V_{DS} \right)$$

$$\text{for } \frac{1}{i_D} = \frac{k_2}{V_{DS}} + \frac{k_1}{V_{DS} - \lambda(V_{GS} - V_{TO})} + \frac{k_3}{V_D + \lambda} \quad \text{for partial fraction}$$

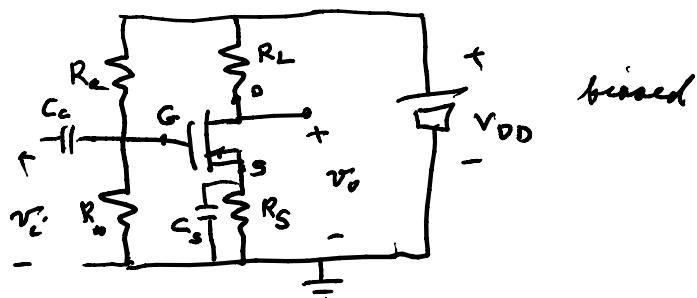
$$\approx \ln \left[ \frac{1}{V_{DS}} \right] \quad \left. \begin{array}{l} \text{still goes to } \infty \text{ if } t_2 \text{ is} \\ \text{when } V_{DS} = 0 \end{array} \right]$$

next time

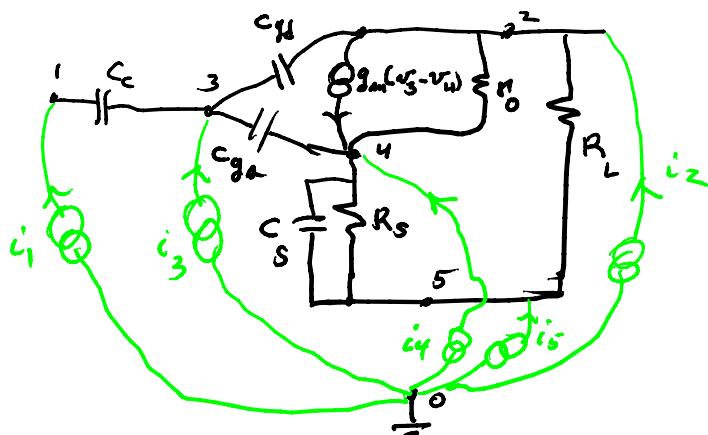
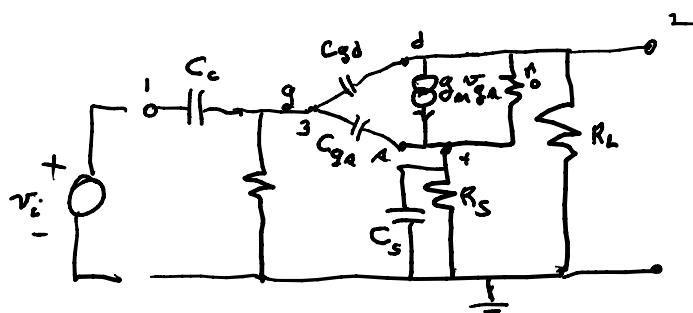
P. 1026 = astable multivibrator

P. 967 = CMOS gates

small signal evaluation ( $\gamma$ -matrix) for  
biased amplifiers



for small signal gain  $\Rightarrow$



$$\begin{bmatrix} i_1 \\ i_2 \\ i_3 \\ i_4 \\ i_5 \end{bmatrix} = \gamma_{\text{ind}} \begin{bmatrix} v_1 \\ v_2 \\ v_3 \\ v_4 \\ v_5 \end{bmatrix} \Rightarrow \text{yields } \begin{bmatrix} i_1 \\ i_2 \end{bmatrix} = \gamma_{2-\text{port}} \begin{bmatrix} v_1 \\ v_2 \end{bmatrix}$$

after some work